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Microbeam analysis — Scanning electron microscopy — Vocabulary

Analyse par microfaisceaux — Microscopie électronique à balayage — Vocabulaire

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ISO copyright office
Case postale 56 • CH-1211 Geneva 20
Tel. + 41 22 749 01 11
Fax + 41 22 749 09 47
E-mail copyright@iso.org
Web www.iso.org

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Foreword

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The main task of technical committees is to prepare International Standards. Draft International Standards adopted by the technical committees are circulated to the member bodies for voting. Publication as an International Standard requires approval by at least 75 % of the member bodies casting a vote.

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ISO 22493 was prepared by Technical Committee ISO/TC 202, *Microbeam analysis*, Subcommittee SC 1, *Terminology*.

Introduction

The scanning electron microscopy (SEM) technique is used to observe and characterize the surface morphology and structure of solid materials, including metal alloys, ceramics, glasses, minerals, polymers, powders, etc., on a spatial scale of micrometer down to nanometer laterally. In addition, three-dimensional structure can be generated by using a combination of focused ion beam and scanning-electron-based analysis techniques. The SEM technique is based on the physical mechanism of electron optics, electron scattering and secondary electron emission.

As a major sub-field of microbeam analysis (MBA), the SEM technique is widely applied in diverse sectors (high-tech industries, basic industries, metallurgy and geology, biology and medicine, environmental protection, trade, etc.) and has a strong business base that needs standardization.

Standardizing the terminology of a technical field is one of the basic prerequisites for development of standards on other aspects of that field.

This International Standard is relevant to the need for an SEM terminology that contains consistent definitions of terms as they are used in the practice of scanning electron microscopy by the international scientific and engineering communities that employ the technique. This International Standard is the second one developed in a package of standards on electron probe microanalysis (EPMA), scanning electron microscopy (SEM), analytical electron microscopy (AEM), energy-dispersive X-ray spectroscopy (EDS), etc., developed or to be developed by Technical Committee ISO/TC 202, *Microbeam analysis*, Subcommittee SC 1, *Terminology*, to cover the complete field of MBA.